2827

## THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

James Allen Cox et al.

Serial No.:

09/751,422

Examiner Unknown

Filed:

December 29, 2000

Group Art Unit 2872

For:

RESONANT REFLECTOR FOR USE WITH OPTOELECTRONIC DEVICES

Docket No.:

1100.1130101 (H16-25181)

### TRANSMITTAL SHEET

Assistant Commissioner for Patents Washington, D.C. 20231

Sir:

We are transmitting herewith the attached:

	Am		

No additional fee required

The fee has been calculated as shown:

	Ine fee h	as been calcul	ated as sho	wn:			
		CLAIMS .	AS AMEN	DED			
	(3)	(4)	(5)	SMALL	ENTITY	OTHER	<b>L</b>
	REMAINING CLAIMS	HIGHEST PAID	EXTRA	RATE	ADD'L FEE	RATE	ADD'L FEE
TOTAL CLAIMS	<b>-</b>	=		x9=	\$	x18=	\$
INDEPEN- DENT CLAIMS	-	=		x39=	\$	x78=	\$
( ) FIRST M	ULTIPLE DEPE	NDENT CLA	[M	+130=	\$	+260=	\$
TOTAL			1	\$		\$	

[]	A check in the amount of \$ is enclosed.
[]	Small entity status of this application under 37 C.F.R. 1.9 and 1.27 has been established by verified statement previously submitted.
[X]	Other: <u>Supplemental Information Disclosure Statement, PTO Form-1449 and cited references</u> .
[X]	Please charge any deficiencies or credit any overpayment in the enclosed fees to Deposit Account No. 50-0413.  By:  Brian N. Tufte  Reg. No38,638

Brian N. Tufte CROMPTON, SEAGER & TUFTE, LLC 331 Second Avenue South Suite 895 Minneapolis, Minnesota 55401-2246

Telephone: (612) 677-9050 Facsimile: (612) 359-9349



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I HEREBY CERTIFY THAT THIS CORRESPONDENCE IS BEING DEPOSITED WITH THE UNITED STATES POSTAL SERVICE AS FIRST CLASS MAJIL IN AN ENVELOPE ADDRESSED TO: ASSISTANT/COMMISSIQUER FOR

ADDRESSED TO: ASSISTANT/COM PATENTS, WASHINGTON, D.C./20231.

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Assistant Commissioner for Patents Washington, D.C. 20231

Dear Sirs:

### SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

Pursuant to the obligations of candor and good faith imposed by 37 C.F.R 1.56, the documents listed on the attached PTO-1449 are hereby disclosed.

No representation is intended to be made hereby that any of the cited references establishes, by itself or in combination with other information, a prima facie case of unpatentability of any claim of the present case.

Respectfully submitted,

James Allen/Cox et al

By their artorney

Dated: June 12, 200)

Brian N. Tufte, Reg. No. 38,638

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FORM PTO-1449	Atty. Docket No.: 1100.1130101 (H16-25181)	Serial No.: 09/751,422	
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION	Applicant: James Allen Cox et al.		
DISCLOSURE STATEMENT	Filing Date	Group Art:	
Nun 1 E	December 29, 2000	2872	

#### FOREIGN PATENT DOCUMENTS

	Document No.	Date	Country	Class	Sub Class	Translation Yes No
AA	DE 4 240 706 A	06/09/1994	Germany			
AB	EP 0 288 184 A	10/26/1988	Europe			
AC	EP 0 776 076 A	05/28/1997	Europe			
AD	JP 60-123084 A	07/01/1985	Japan			Yes (Abstract only)
 AE	JP 02-054981 A	02/23/1990	Japan			Yes (Abstract only)

OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)

Guenter et al., "Reliability of Proton Implanted VCSELs for Data Communications", Invited paper, SPIE, Vol. 2683, OE LASE 96; Photonics West: Fabrication, Testing and Reliability of Semiconductor Lasers, (SPIE, Bellingham, WA 1996).
Hibbs-Brenner et al., "Performance, Uniformity and Yield of 850nm VCSELs Deposited by MOVPE", IEEE Phot. Tech. Lett., Vol. 8, No. 1, pp. 7-9, January 1996.
Hornak et al., "Low-Termperature (10K-300K) Characterization of MOVPE-Grown Vertical-Cavity Surface-Emitting Lasers", <u>Photon. Tech. Lett.</u> , Vol. 7, No. 10, pp. 1110-1112, October 1995.
Huffaker et al., "Lasing Characteristics of Low Threshold Microcavity Layers Using Half-Wave Spacer Layers and Lateral Index Confinement", <u>Appl. Phys. Lett.</u> , Vol. 66, No. 14, pp.1723-1725, April 3, 1995.
K.L. Lear et al., "Selectively Oxidized Vertical Cavity Surface-Emitting Lasers with 50% Power Conversion Efficiency", Elec. Lett., Vol. 31, No. 3 pp. 208-209, February 2, 1995.
Lehman et al., "High Frequency Modulation Characteristics of Hybrid Dielectric/AlGaAs Mirror Singlemode VCSELs", Electronic Letters, vol. 31, No. 15, July 20, 1995, pp. 1251-1252.
Magnusson, "Integration of Guided-Mode Resonance Filters and VCSELs", Electo-Optics Research Center, Department of Electrical Engineering, University of Texas at Arlington, May 6, 1997.

**EXAMINER:** 

DATE CONSIDERED:

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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JUN '	RADE MARIE M	<i>c</i>		
AM	AADEN'' Morgan et al., "Hybrid Dielectric/AlGaAs Mi Laser", Appl. Phys. Lett., Vol. 60, No. 8, pp.		Top-Surface Emittin	
AN	Morgan et al., "One Watt Vertical Cavity Surface Emitting Laser", <u>Electron. Lett.</u> , Vol. 29, No. 2, pp. 206-207, January 21, 1993			
AO	Morgan et al., "Producible GaAs-based MOVPE-Grown Vertical-Cavity Top-Surface Emitting Lasers with Record Performance", Elec. Lett., Vol. 31, No. 6, pp. 462-464, March 16, 1995.			
AP	Morgan et al., "Spatial-Filtered Vertical-Cavity Top Surface-Emitting Lasers", CLEO, 1993, pp. 138-139. (No worth)			
AQ	Morgan et al., "Vertical Cavity Surface Emitting Laser Arrays: Come of Age,", Invited paper, SPIE, Vol. 2683-04, OE LASE 96; Photonics West: Frabrication, Testing and Reliablity of Semiconductor Lasers, (SPIE > Bellingham, WA, 1996). (No much)			
AR	S.S. Wang and R. Magnusson, "Multilayer Waveguide-Grating Filters", Appl. Opt., Vol. 34, No. 14, pp. 2414-20, 1995. (No month)			
AS	S.S. Wang and R. Magnusson, "Theory and Applications of Guided-Mode Resonance Filters", Appl. Opt., Vol. 32, No. 14, pp. 2606-13/1993. (Mo Worth)			
AT	Schubert, "Resonant Cavity Light-Emitting Diode", Appl. Phys. Lett., Vol. 60, No. 8, pp. 921-923, February 24, 1992.			
AU	Y. M. Yang et al., "Ultralow Threshold Current Vertical Cavity Surface Emitting Lasers Obtained with Selective Oxidation", Elect. Lett., Vol. 31, No. 11, pp. 886-888, May 25, 1995.			
AV	Yablonovitch et al., "Photonic Bandgap Structures", J. Opt. Soc. Am. B., Vol. 10, No. 2, pp. 283-			

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295, February 1993.

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Young et al., "Enhanced Performance of Offset-Gain High Barrier Vertical-Cavity Surface-Emitting Lasers", IEEE J. Quantum Electron., Vol. 29, No. 6, pp. 2013-2022, June 1993. Smith, R.E. et al., "Polarization-Sensitive Subwavelength Antireflection Surfaces on a

Semiconductor for 975 NM, Optics Letters, Vol. 21, No. 15, August 1, 1996, pp. 1201-1203.

Journal of Lightwave Technology, Vol. 12, No. 11, November 1, 1994, pp. 1971-1975.

Suning Tang et al., "Design Limitations of Highly Parallel Free-Space Optical Interconnects Based

on Arrays of Vertical Cavity Surface-Emitting Laser Diodes, Microlenses, and Photodetectors",

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BA	of the SPIE, The International Society for Optical Engineering, Diffractive and Holographic Device Technologies and Applications V, San Jose, California, January 28-29, 1998, Vol. 3291, pages 70-71.  BA Martinsson et al., "Transverse Mode Selection in Large-Area Oxide-Confined Vertical-Cavity Surface-Emitting Lasers Using a Shallow Sarface Relief", IEEE Photon. Technol. Lett., 11(12),					
(BB)	Choquette et al., "Lithographically-Defined Gain Apertures Within Selectively Oxidized VCSELs", paper CtuL6, Conference on Lasers and Electro-Optics, San Francisco, California (2000).					
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	"Surface-Emitting Microlasers for Photonic Switching and Interchip Connections", Optical Engineering, 29, pp. 210-214, March 1990.					
	G. Shtengel et al., "High-Speed Vertical-Cavity Surface-Emitting Lasers", Photon. Tech. Lett., Vol. 5, No. 12, pp. 1359-1361 (December 1993).					

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